

# Accutek Microcircuit Corporation

**AK632128AW / AK632128AZ**  
131,072 x 32 Bit CMOS/BiCMOS  
Static Random Access Memory

## DESCRIPTION

The Accutek AK632128W SRAM Module consists of fast high performance SRAMs mounted on a low height, 64 pin SIM or ZIP PCB. The module utilizes four 32 pin 128K x 8 SRAMs in 300 mil SOJ packages and four decoupling capacitors mounted on the front side of a printed circuit board.

The SRAMs used have common I/O functions and single output enable functions. Also, four separate chip select ( $\overline{CE}$ ) connections are used to independently enable the four bytes. The modules can be supplied in a variety of access time values from 7nSEC to 35nSEC in CMOS or BiCMOS technology.

The Accutek module is designed to have a maximum seated height of 0.600 inch SIM or 0.520 inch ZIP to provide for the lowest height off the board. Each conforms to JEDEC-standard sizes and pin-out configurations. Using two pins for module density identification,  $PD_0$  and  $PD_1$ , minimizes interchangeability and design considerations when changing from one module size to the other in customer applications.

## FEATURES

- 131,072 x 32 bit organization
- JEDEC Standard 64 pin SIM or ZIP format
- Access times as fast as 7nSEC
- TTL compatible inputs and outputs
- Very low profile, 0.600 inch MAX seated height SIM Version
- Very low profile, 0.520 inch MAX seated height ZIP Version
- Single 5 volt power supply - AK632128AW, AK632128AZ
- Single 3.3 volt power supply - AK632128AW/3.3, AK632128AZ/3.3

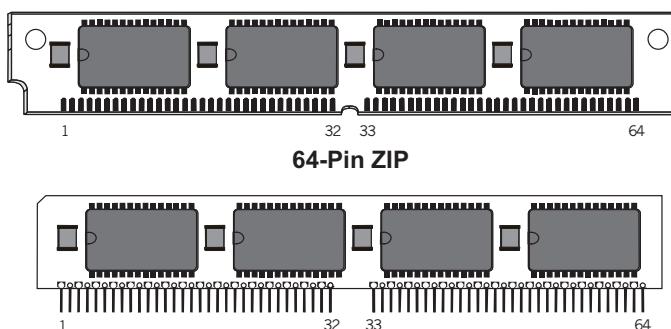
## PIN NOMENCLATURE

A <sub>0</sub> - A <sub>16</sub>	Address Inputs
$\overline{CE}_1$ - $\overline{CE}_4$	Chip Enable
DQ <sub>1</sub> - DQ <sub>32</sub>	Data In/Data Out
$\overline{OE}$	Output Enable
PD <sub>0</sub> - PD <sub>1</sub>	Presence Detect
Vcc	Power Supply
Vss	Ground
$\overline{WE}$	Write Enable
NC	No Connect

## PIN ASSIGNMENT

PIN #	SYMBOL	PIN #	SYMBOL	PIN #	SYMBOL	PIN #	SYMBOL
1	Vss	17	A <sub>2</sub>	33	$\overline{CE}_4$	49	A <sub>4</sub>
2	PD <sub>0</sub>	18	A <sub>9</sub>	34	$\overline{CE}_3$	50	A <sub>11</sub>
3	PD <sub>1</sub>	19	DQ <sub>13</sub>	35	NC	51	A <sub>5</sub>
4	DQ <sub>1</sub>	20	DQ <sub>5</sub>	36	A <sub>16</sub>	52	A <sub>12</sub>
5	DQ <sub>9</sub>	21	DQ <sub>14</sub>	37	$\overline{OE}$	53	Vcc
6	DQ <sub>2</sub>	22	DQ <sub>6</sub>	38	Vss	54	A <sub>13</sub>
7	DQ <sub>10</sub>	23	DQ <sub>15</sub>	39	DQ <sub>25</sub>	55	A <sub>6</sub>
8	DQ <sub>3</sub>	24	DQ <sub>7</sub>	40	DQ <sub>17</sub>	56	DQ <sub>21</sub>
9	DQ <sub>11</sub>	25	DQ <sub>16</sub>	41	DQ <sub>26</sub>	57	DQ <sub>29</sub>
10	DQ <sub>4</sub>	26	DQ <sub>8</sub>	42	DQ <sub>18</sub>	58	DQ <sub>22</sub>
11	DQ <sub>12</sub>	27	Vss	43	DQ <sub>27</sub>	59	DQ <sub>30</sub>
12	Vcc	28	$\overline{WE}$	44	DQ <sub>19</sub>	60	DQ <sub>23</sub>
13	A <sub>0</sub>	29	A <sub>15</sub>	45	DQ <sub>28</sub>	61	DQ <sub>31</sub>
14	A <sub>7</sub>	30	A <sub>14</sub>	46	DQ <sub>20</sub>	62	DQ <sub>24</sub>
15	A <sub>1</sub>	31	$\overline{CE}_2$	47	A <sub>3</sub>	63	DQ <sub>32</sub>
16	A <sub>8</sub>	32	$\overline{CE}_1$	48	A <sub>10</sub>	64	Vss

## Top View 64-Pin SIMM

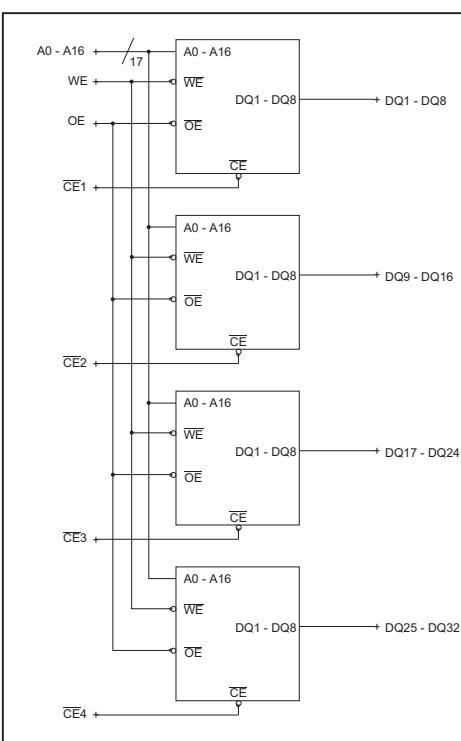


- Common I/O, single OE functions with four separate chip selects ( $\overline{CE}$ )
- Presence Detect  $PD_0$  and  $PD_1$  for identifying module density
- Downward compatible with 32K x 32 (AK63232) and 64K x 32 AK63264)
- Upward compatible with 256K x 32 (AK632256), 512K x 32 (AK632512) and 1 Meg x 32 (AK6321024)
- Operating free air temperature 0° to 70°C

## ELECTRICAL SPECIFICATIONS

Timing diagrams and basic electrical characteristics are those of the standard 128K x 8 SRAMs used to construct these modules. Accutek's module design allows the flexibility of selecting industry-compatible 128K x 8 SRAMs from at least seven semiconductor manufacturers.

## FUNCTIONAL DIAGRAM



## MODULE OPTIONS

Leadless SIM: AK632128AW

Leaded ZIP: AK632128AZ

PD<sub>0</sub> = Open  
PD<sub>1</sub> = Open

## **ORDERING INFORMATION**

## PART NUMBER CODING INTERPRETATION

**Position** 1 2 3 4 5 6 7 8

- 1 Product**  
**AK = Accutek Memory**

**2 Type**  
4 = Dynamic RAM  
5 = CMOS Dynamic RAM  
6 = Static RAM

**3 Organization/Word Width**  
1 = by 1    16 = by 16  
4 = by 4    32 = by 32  
8 = by 8    36 = by 36  
9 = by 9

**4 Size/Bits Depth**  
64 = 64K        4096 = 4 MEG  
256 = 256K      8192 = 8 MEG  
1024 = 1 MEG    16384 = 16 MEG

**5 Package Type**  
**G = Single In-Line Package (SIP)**  
**S = Single In-Line Module (SIM)**  
**D = Dual In-Line Package (DIP)**  
**W = .050 inch Pitch Edge Connect**  
**Z = Zig-Zag In-Line Package (ZIP)**

**6 Special Designation**  
**P = Page Mode**  
**N = Nibble Mode**  
**K = Static Column Mode**  
**W = Write Per Bit Mode**  
**V = Video Ram**

**7 Separator**  
- = Commercial  $0^{\circ}\text{C}$  to  $+70^{\circ}\text{C}$   
**M = Military Equivalent Screened**  
( $-55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ )  
**I = Industrial Temperature Tested**  
( $-45^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ )  
**X = Burned In**

**8 Speed (first two significant digits)**  
**DRAMs                   SRAMs**  
50 = 50 nS        8 = 8 nS  
60 = 60 nS        10 = 10 nS  
70 = 70 nS        12 = 12 nS  
80 = 80 nS        15 = 15 nS

The numbers and coding on this page do not include all variations available but are shown as examples of the most widely used variations. Contact Accutek if other information is required.

## **EXAMPLES:**

**AK632128AW-10**

128K x 32, 15 nSEC SRAM Module, SIM Configuration

AK632128AZ-12

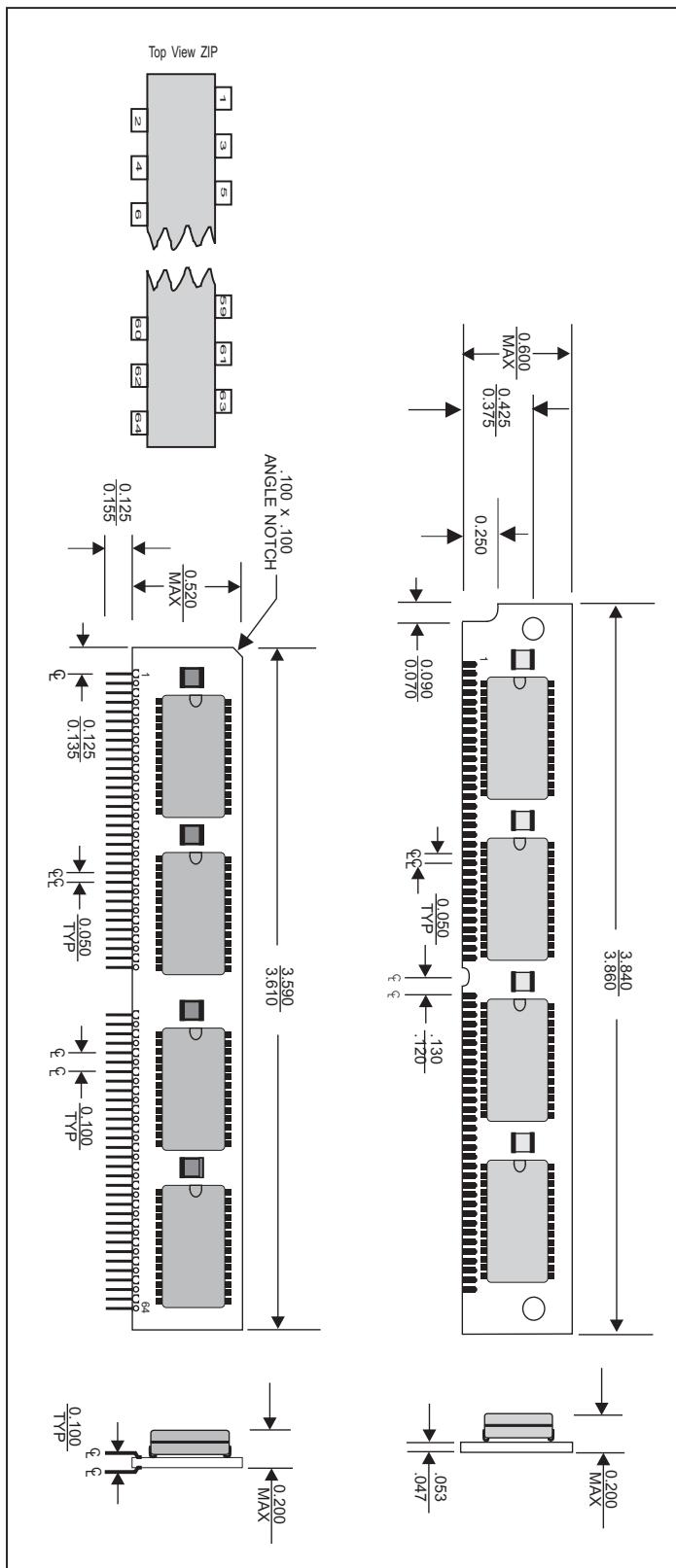
## 128K x 32, 12 nSEC SRAM Module, ZIP Configuration



**ACCUTEK MICROCIRCUIT CORPORATION**  
BUSINESS CENTER at NEWBURYPORT  
2 NEW PASTURE ROAD, SUITE 1  
NEWBURYPORT, MA 01950-4054  
VOICE: 978-465-6200 FAX: 978-462-3396  
Email: sales@accutekmicro.com  
Internet: www.accutekmicro.com

## **MECHANICAL DIMENSIONS**

## Inches



Accutek reserves the right to make changes in specifications at any time and without notice. Accutek does not assume any responsibility for the use of any circuitry described; no circuit patent licenses are implied. Preliminary data sheets contain minimum and maximum limits based upon design objectives, which are subject to change upon full characterization over the specific operating conditions.